Advance Information

SWITCHMODE™ Series

NPN Bipolar Power Transistor

The MJE8503A transistor is designed for high voltage, high speed, power switching in inductive circuits where fall time is critical. They are suited for line operated switchmode applications such as:

- Switching Regulators
- Inverters
- · Solenoid and Relay Drivers
- Motor Controls
- · Deflection Circuits

Featuring

- 1500 Volt Collector-Base Breakdown Capability
- Fast Switching:
 - 180 ns Typical Fall Times

 Fast Switching: 180 ns Typical Fall Times 450 ns Typical Crossover Times 1.2 μs Typical Storage Times Low Collector-Emitter Leakage Current — 100 μA Max @ 1500 VCES MAXIMUM RATINGS (T_C = 25°C unless otherwise noted) 							
Rating	Symbol	Value	Unit				
Collector-Emitter Voltage	VCEO(sus)	700	Vdc				
Collector-Emitter Voltage	V _{CES}	1500	Vdc				
Collector-Base Voltage	V _{CBO}	1500	Vdc				
Emitter-Base Voltage	V _{EBO}	5.0	Vdc				
Collector Current — Continuous — Peak (1)	lc	5.0 10	Adc				
Collector Current — Continuous — Peak	I _B	4.0 4.0	Adc				
Total Power Dissipation @ T _C = 25°C @ T _C = 100°C Derate above 25°C	P _D	80 21 0.8	Watts W/°C				
Operating and Storage Temperature Range	T _J , T _{Stg}	-65 to +125	°C				

THERMAL CHARACTERISTICS

Characteristic	Symbol	Max	Unit
Thermal Resistance, Junction to Case	$R_{\theta JC}$	1.25	°C/W
Maximum Lead Temperature for Soldering Purposes 1/8" from Case for 5 sec.	TL	275	°C

⁽¹⁾ Pulse Test: Pulse Width = 5.0 ms, Duty Cycle < 10%.

SWITCHMODE is a trademark of Motorola Inc.

This document contains information on a new product. Specifications and information herein are subject to change without notice.

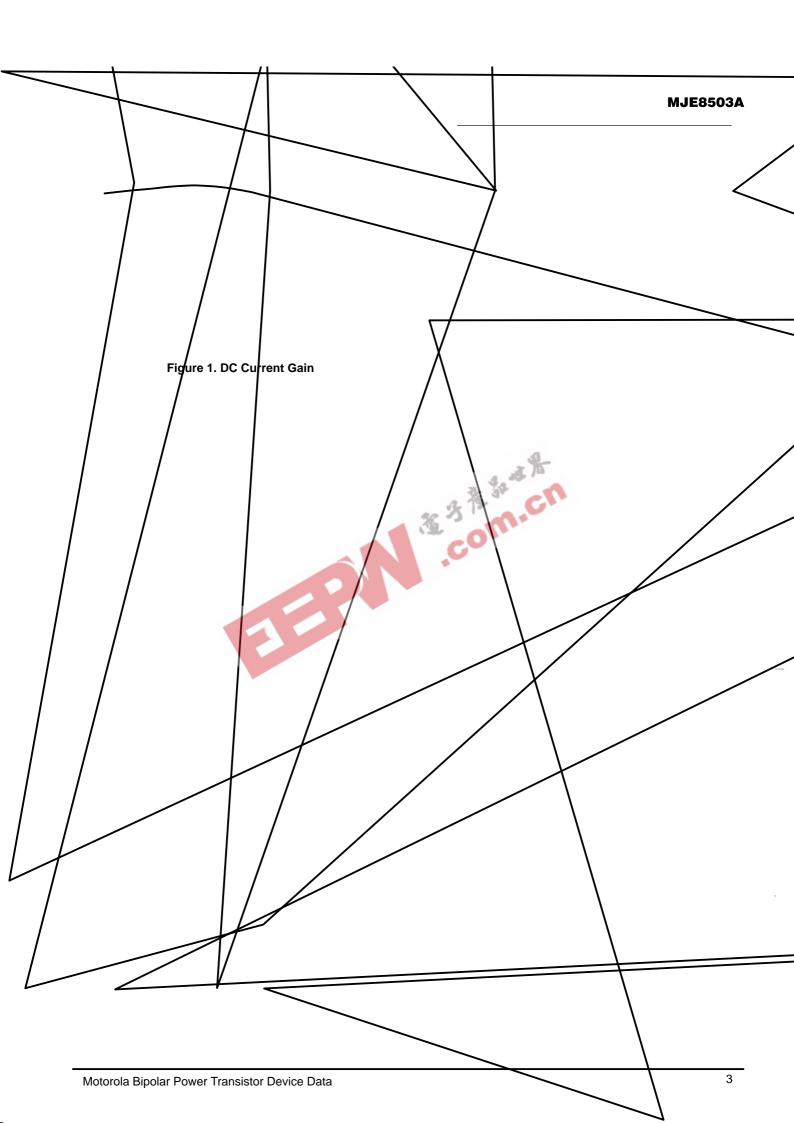
Preferred devices are Motorola recommended choices for future use and best overall value.

MJE8503A

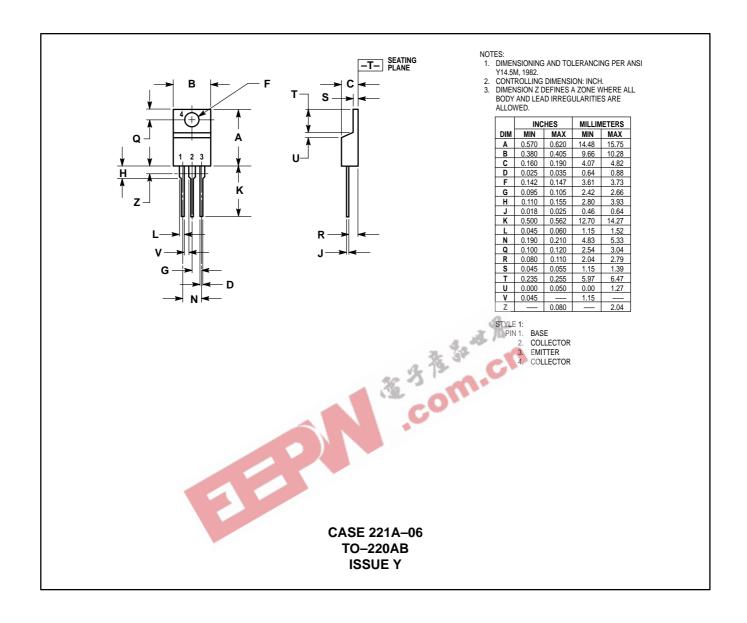
ELECTRICAL CHARACTERISTICS ($T_C = 25^{\circ}C$ unless otherwise noted)

	Characteristic	Symbol	Min	Тур	Max	Unit
OFF CHARACTERISTICS					•	•
Collector-Emitter Sustair (I _C = 100 mAdc, I _B = 0		VCEO(sus)	700	_	_	Vdc
Collector Cutoff Current (V _{CE} = 1500 Vdc, V _{BI} (V _{CE} = 1500 Vdc, V _{BI}		ICES	_	_	0.1 2.0	mAdc
Collector Cutoff Current (VCE = 1500 Vdc, RBI	E = 50 Ohms, T _C = 100°C)	ICER	_	_	5.0	mAdc
Emitter Cutoff Current (VEB = 6.0 Vdc, I _C = 0	0)	I _{EBO}	_	_	1.0	mAdc
SECOND BREAKDOWN					•	•
Second Breakdown Colle	ector with Base Forward Biased	I _{S/b}		See Figure 2		
ON CHARACTERISTICS						
DC Current Gain (I _C = 1.0 Adc, V _{CE} = 5 (I _C = 4.5 Adc, V _{CE} = 5	5.0 Vdc) 5.0 Vdc)	hFE	7.5 2.25	_ _	_ _	_
Base-Emitter Saturation ($I_C = 2.5 \text{ Adc}$, $I_B = 1.0$ ($I_C = 4.5 \text{ Adc}$, $I_B = 2.0$	Vdc)	V _{BE} (sat)	<u></u>	_ _	1.5 1.5	Vdc
Collector-Emitter Saturat (I _C = 2.5 Adc, I _B = 1.0 (I _C = 4.5 Adc, I _B = 2.0	Vdc)	VCE(sat)	C.	_ _	2.0 3.0	Vdc
DYNAMIC CHARACTERI	STICS	60.			•	
Current-Gain — Bandwid (IC = 0.1 Adc, VCE = 5	dth Product 5.0 Vdc, f _{test} = 1.0 MHz)	fΤ	_	7.0	_	MHz
Output Capacitance (V _{CB} = 10 Vdc, I _E = 0	, f _{test} = 0.1 MHz)	C _{ob}	_	125	_	pF
SWITCHING CHARACTE	RISTICS					
Resistive Load (Table 1)						
Delay Time		t _d	1	0.06	0.2	μs
Rise Time	$(I_C = 2.5 \text{ Adc}, I_B = 1.0 \text{ Adc}, V_{CC} = 500 \text{ Vdc}$ $V_{BE(off)} = 5.0 \text{ Vdc}, t_p = 50 \text{ μs})$	t _r	_	0.08	2.0	
Storage Time		t _S	_	1.2	4.0	
Fall Time		t _f	_	0.7	2.0	
Inductive Load (Table 1)						
Storage Time	$(I_C = 2.5 \text{ Adc}, I_B = 1.0 \text{ Adc}, V_{clamp} = 500 \text{ Vdc}$ $V_{BE(off)} = 5.0 \text{ Vdc}, t_p = 50 \text{ μs})$	t _{SV}	_	1.2	_	μs
Crossover Time		t _C	_	0.45	_	
Fall Time		t _{fi}	_	0.18	_]

⁽¹⁾ Pulse Test: Pulse Width = $300 \mu s$, Duty Cycle $\leq 2\%$



PACKAGE DIMENSIONS



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